
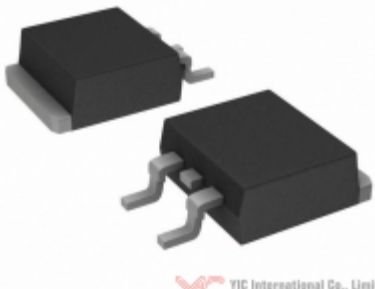









	<h2>IRFBC30AS</h2>
	<p><b>Hersteller-Teilenummer:</b> IRFBC30AS</p> <p><b>Hersteller / Marke:</b> Vishay / Siliconix</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 600V 3.6A D2PAK</p> <p><b>Datenblätter:</b>  <a href="#">IRFBC30AS.pdf</a></p> <p><b>RoHs Status:</b> Enthält Blei / RoHS nicht konform</p> <p><b>Lagerzustand:</b> New original, 1043 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	IRFBC30AS
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 600V 3.6A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	1043 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D2PAK
Verlustleistung (max)	74W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.6A (Tc)
Rds On (Max) @ Id, Vgs	2.2 Ohm @ 2.2A, 10V
VGS (th) (Max) @ Id	4.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	23nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	510pF @ 25V
Verpackung	Tube

IRFBC30AS ist neu im Original, Suche IRFBC30AS Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IRFBC30AS Vishay / Siliconix mit Garantie und Vertrauen. Anfrage IRFBC30AS: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>IRFBC30APBF</b> Vishay / Siliconix MOSFET N-CH 600V 3.6A TO-220AB</p>	 <p><b>IRFBC30ALPBF</b> Electro-Films (EFI) / Vishay MOSFET N-CH 600V 3.6A TO-262</p>	 <p><b>IRFBC30AL</b> Vishay / Siliconix MOSFET N-CH 600V 3.6A TO-262</p>	 <p><b>IRFBC30ASPBF</b> Electro-Films (EFI) / Vishay MOSFET N-CH 600V 3.6A D2PAK</p>
 <p><b>IRFBC30ASTRL</b> Electro-Films (EFI) / Vishay MOSFET N-CH 600V 3.6A D2PAK</p>	 <p><b>IRFBC30ASPBF</b> Vishay / Siliconix MOSFET N-CH 600V 3.6A D2PAK</p>	 <p><b>IRFBC30AS</b> Electro-Films (EFI) / Vishay MOSFET N-CH 600V 3.6A D2PAK</p>	 <p><b>IRFBC30ALPBF</b> Vishay / Siliconix MOSFET N-CH 600V 3.6A TO-262</p>

### heiße Teile

Mehr

 IRFB9N65	 IRFB9N65A	 IRFB9N65A	 IRFB9N65APBF	 IRFB9N65APBF
 IRFBA1404P	 IRFBA1404PPBF	 IRFBA1405P	 IRFBA22N50A	 IRFBC20-030
 IRFBC20LPBF	 IRFBC20LPBF	 IRFBC20PBF	 IRFBC20PBF	 IRFBC20SPBF
 IRFBC20SPBF	 IRFBC20STRL	 IRFBC20STRL	 IRFBC20STRLPBF	 IRFBC20STRLPBF
 IRFBC20STRR	 IRFBC20STRR	 IRFBC30ALPBF	 IRFBC30ALPBF	 IRFBC30AS
 IRFBC30ASPBF	 IRFBC30ASPBF	 IRFBC30ASTRL	 IRFBC30ASTRL	 IRFBC30ASTRR
 IRFBC30ASTRR	 IRFBC30ASTRRPBF	 IRFBC30ASTRRPBF	 IRFBC30LPBF	 IRFBC30LPBF
 IRFBC30LTRR	 IRFBC30PBF	 IRFBC30PBF	 IRFBC30S	 IRFBC30S
 IRFBC30STRLPBF	 IRFBC30STRLPBF	 IRFBC30STRR	 IRFBC30STRR	 IRFBC40A
 IRFBC40A	 IRFBC40APBF	 IRFBC40APBF	 IRFBC40AS	 IRFBC40AS

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